



### Data Sheet

### March 2009

# 4A, 1200V Ultrafast Diodes

The RURD4120S9A\_F085 are ultrafast diodes with soft recovery characteristics ( $t_{rr} < 70$ ns). They have low forward voltage drop and are silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/ clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Formerly developmental type TA49036.

# **Ordering Information**

PART NUMBER	PACKAGE	BRAND
RURD4120S9A_F085	TO-252	UR4120

# Symbol



## Features

•	Ultrafast with Soft	Recovery													<70ns	5
---	---------------------	----------	--	--	--	--	--	--	--	--	--	--	--	--	-------	---

- Avalanche Energy Rated
- Planar Construction
- Qualified to ACE Q101
- RoHS Compliant

### Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

## Packaging

#### JEDEC STYLE TO-252



### Absolute Maximum Ratings T<sub>C</sub> = $25^{\circ}$ C, Unless Otherwise Specified

	RURD4120S9A_F085	UNITS
Peak Repetitive Reverse Voltage	1200	V
Working Peak Reverse VoltageV <sub>RWM</sub>	1200	V
DC Blocking Voltage	1200	V
Average Rectified Forward Current	4	А
Repetitive Peak Surge Current I <sub>FRM</sub> (Square Wave, 20kHz)	8	А
Nonrepetitive Peak Surge Current I <sub>FSM</sub> (Halfwave, 1 Phase, 60Hz)	40	А
Maximum Power Dissipation	50	W
Avalanche Energy (See Figures 10 and 11) E <sub>AVL</sub>	10	mJ
Operating and Storage Temperature	-65 to 175	°C



SYMBOL	TEST CONDITION	MIN	ТҮР	MAX	UNITS
V <sub>F</sub>	$I_{F} = 4A$	-	-	2.1	V
	I <sub>F</sub> = 4A, T <sub>C</sub> = 150 <sup>o</sup> C	-	-	1.9	V
I <sub>R</sub>	V <sub>R</sub> = 1200V	-	-	100	μΑ
	V <sub>R</sub> = 1200V, T <sub>C</sub> = 150 <sup>o</sup> C	-	-	500	μA
t <sub>rr</sub>	$I_F = 1A$ , $dI_F/dt = 200A/\mu s$	-	-	70	ns
	$I_F = 4A$ , $dI_F/dt = 200A/\mu s$	-	-	90	ns
t <sub>a</sub>	$I_F = 4A$ , $dI_F/dt = 200A/\mu s$	-	40	-	ns
t <sub>b</sub>	$I_{F} = 4A$ , $dI_{F}/dt = 200A/\mu s$	-	28	-	ns
Q <sub>RR</sub>	$I_F = 4A$ , $dI_F/dt = 200A/\mu s$	-	335	-	nC
CJ	V <sub>R</sub> = 10V, I <sub>F</sub> = 0A	-	15	-	pF
$R_{ extsf{ heta}JC}$		-	-	3	°C/W

### Electrical Specifications T<sub>C</sub> = 25°C, Unless Otherwise Specified

DEFINITIONS

 $V_F$  = Instantaneous forward voltage (pw = 300µs, D = 2%).

I<sub>R</sub> = Instantaneous reverse current.

 $t_{rr}$  = Reverse recovery time (See Figure 9), summation of  $t_a + t_b$ .

 $t_a$  = Time to reach peak reverse current (See Figure 9).

 $t_b$  = Time from peak I<sub>RM</sub> to projected zero crossing of I<sub>RM</sub> based on a straight line from peak I<sub>RM</sub> through 25% of I<sub>RM</sub> (See Figure 9).

Q<sub>RR</sub> = Reverse recovery time.

 $C_J$  = Junction capacitance.

 $R_{\theta JC}$  = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

# **Typical Performance Curves**

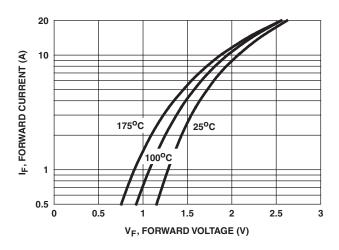


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

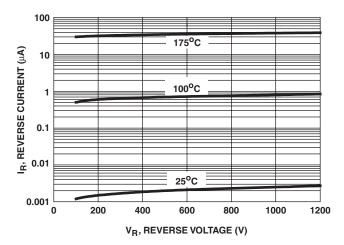


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

# Typical Performance Curves (Continued)

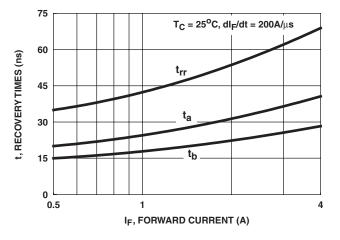
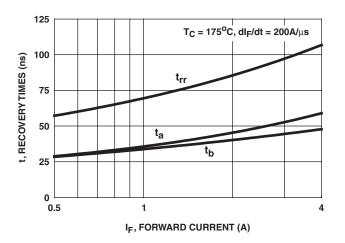


FIGURE 3. t<sub>rr</sub>, t<sub>a</sub> AND t<sub>b</sub> CURVES vs FORWARD CURRENT





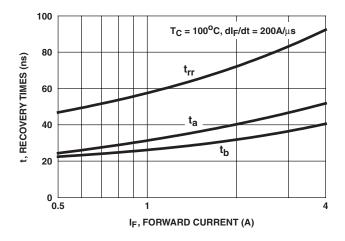


FIGURE 4.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

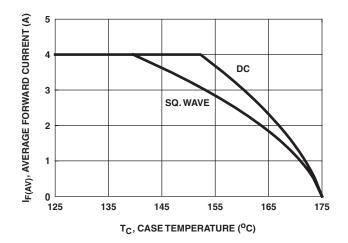


FIGURE 6. CURRENT DERATING CURVE

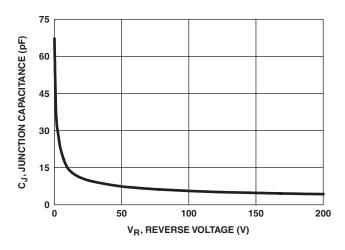


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

# Test Circuits and Waveforms

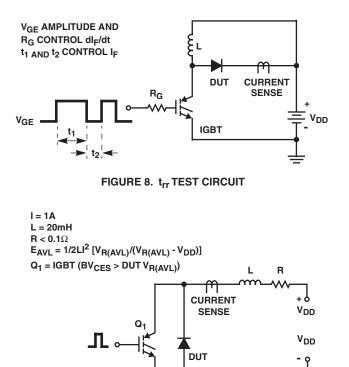


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

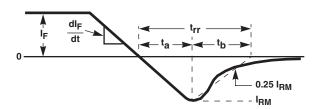


FIGURE 9. trr WAVEFORMS AND DEFINITIONS

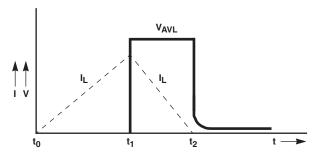


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS



proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild of from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

#### PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.
		Rev.